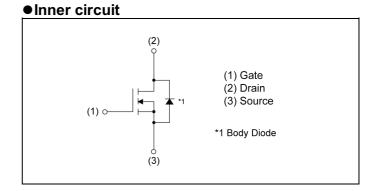
Nch 600V 11A Power MOSFET

V _{DSS}	600V
R _{DS(on)} (Max.)	390mΩ
I _D	±11A
P _D	124W

_

Outline
TO-252



Features

- 1) Low on-resistance
- 2) Low radiation noise
- 3) Drive circuits can be simple
- 4) Parallel use is easy
- 5) Pb-free plating; RoHS compliant

Packaging specifications

- i dekaging epeemeanene	
Packing	Embossed Tape
Packing code	TL1
Marking	R6011E
Basic ordering unit (pcs)	2500

Application

Switching

● **Absolute maximum ratings** (T_a = 25°C ,unless otherwise specified)

Parameter		Symbol	Value	Unit
Drain - Source voltage		V_{DSS}	600	V
Continuous drain current (T _c = 25	5°C)	I _D *1	±11	Α
Pulsed drain current		I _{DP} *2	±22	А
Cata Cauraa valtaga	static	V	±20	V
Gate - Source voltage	AC(f>1Hz)	V_{GSS}	±30	V
Avalanche current, single pulse		I _{AS}	1.8	А
Avalanche energy, single pulse		E _{AS} *3	210	mJ
Power dissipation (T _c = 25°C)	P _D	124	W	
Junction temperature	T _j	150	°C	
Operating junction and storage te	T _{stg}	-55 to +150	°C	

●Thermal resistance

Downwortow	Cymah al	Values			1.1
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R _{thJC} *4	-	-	1.0	°C/W
Thermal resistance, junction - ambient	R _{thJA}	-	-	147	°C/W
Soldering temperature, wavesoldering for 10s	T _{sold}	-	-	265	°C

●Electrical characteristics (T_a = 25°C)

Parameter	Cumb al	Conditions	Values			Unit	
- Farameter	Symbol	Conditions	Min.	Тур.	Max.	Offic	
Drain - Source breakdown voltage	V _{(BR)DSS}	$V_{GS} = 0V$, $I_D = 1mA$	600	-	-	V	
		V _{DS} = 600V, V _{GS} = 0V					
Zero gate voltage drain current	I _{DSS}	$T_j = 25^{\circ}C$	-	-	100	μΑ	
		$T_j = 125^{\circ}C$	-	-	1000		
Gate - Source leakage current	I _{GSS}	V _{GS} = ±20V, V _{DS} = 0V	-	-	±100	nA	
Gate threshold voltage	V _{GS(th)}	V_{DS} = 10V, I_D = 1mA	2	1	4	٧	
		V _{GS} = 10V, I _D = 3.8A					
Static drain - source on - state resistance	R _{DS(on)} *6	$T_j = 25^{\circ}C$	-	340	390	mΩ	
		$T_j = 125^{\circ}C$	-	720	-		
Gate resistance	R_{G}	f = 1MHz, open drain	-	7.7	-	Ω	

● Electrical characteristics (T_a = 25°C)

Darramatar	Cymah al	Conditions	Values			Linit	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Forward Transfer Admittance	Y _{fs} *6	$ Y_{fs} ^{*6}$ $V_{DS} = 10V, I_D = 5.5A$		6.0	-	S	
Input capacitance C _{iss} V _G		V _{GS} = 0V	-	670	-		
Output capacitance	C _{oss}	V _{DS} = 25V	-	570	-	pF	
Reverse transfer capacitance	C _{rss}	f = 1MHz		70	-		
Turn - on delay time	$t_{d(on)}^{*6}$ $V_{DD} \simeq 300V, V_{GS} = 10V$		-	25	-		
Rise time	t _r *6	I _D = 5.5A	-	40	-	20	
Turn - off delay time $t_{d(off)}{}^{*6}$		$R_L \simeq 54.9\Omega$	-	90	-	ns	
Fall time	t _f *6	$R_G = 10\Omega$	-	35	-		

● Gate charge characteristics (T_a = 25°C)

Davamatar	Company of	Conditions	Values			l limit
Parameter	Symbol Conditions		Min.	Тур.	Max.	Unit
Total gate charge	Q_g^{*6}	V _{DD} ≈ 300V	-	32	-	
Gate - Source charge	Q _{gs} *6	I _D = 11A	-	5	-	nC
Gate - Drain charge	Q _{gd} *6	V _{GS} = 10V	-	17	-	
Gate plateau voltage	V _(plateau)	V _{DD} ≈ 300V, I _D = 11A	-	6.0	-	V

^{*1} Limited only by maximum channel temperature allowed

^{*2} Pw ≤ 10µs, Duty cycle ≤ 1%

^{*3} L \doteqdot 100mH, V_{DD}=50V, R_G=25 Ω , STARTING T_i=25 $^{\circ}$ C

^{*4} T_C=25°C

^{*5} Mounted on a epoxy PCB FR4 (25mm x 27mm x 0.8mm)

^{*6} Pulsed

● Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

Parameter	Symbol	Conditions	Values			Unit	
- Farameter	Symbol	Conditions	Min.	Тур.	Max.	UIIIL	
Source current I _S *1		T - 25°C	1	-	11	Α	
Pulsed source current	I _{SP} *2	T _C = 25°C	1	-	22	Α	
Source-Drain voltage	V _{SD} *6	V _{GS} = 0V, I _S = 11A	-	-	1.5	V	
Reverse recovery time	t _{rr} *6		-	430	-	ns	
Reverse recovery charge	Q _{rr} *6	$I_{S} = 11A$ di/dt = 100A/µs	-	4.5	-	μC	
Peak reverse recovery current	_{rr} *6		-	22	-	Α	

Fig.1 Power Dissipation Derating Curve

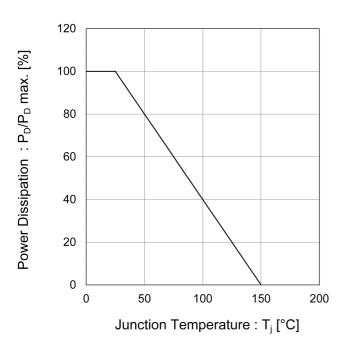


Fig.2 Drain Current Derating
Curve vs. Junction Temperature

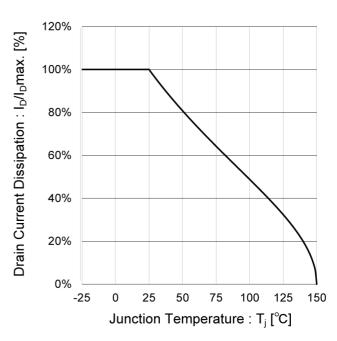


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

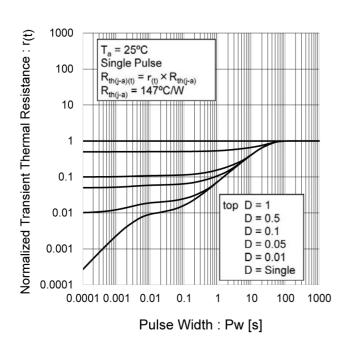
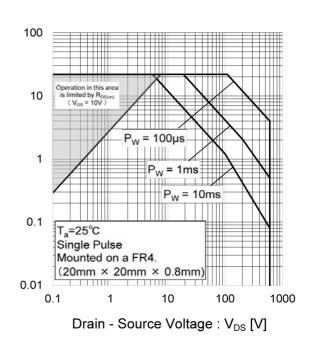


Fig.4 Maximum Safe Operating Area



Drain Current : I_D [A]

Fig.5 Avalanche Energy Derating
Curve vs. Junction Temperature

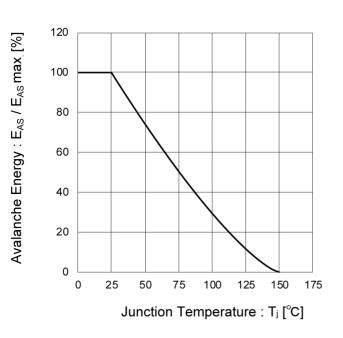


Fig.6 Breakdown Voltage vs.
Junction Temperature

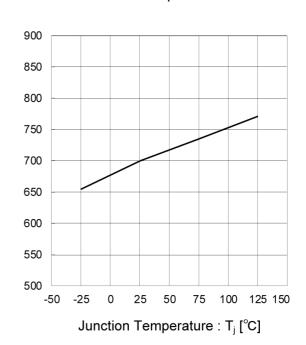
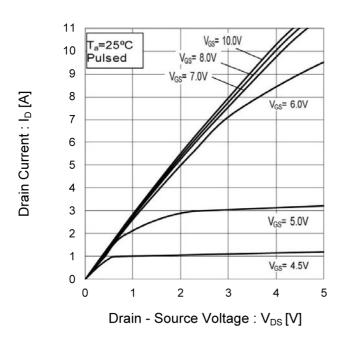


Fig.7 Typical Output Characteristics(I)



Drain Current : I_D [A]

Drain-Source Breakdown Voltage: V_{(BR)DSS} [V]

11 V_{GS}= 10.0V T_a=25℃ 10 V_{GS}= 8.0V Pulsed 9 V_{GS}= 7.0V V_{GS}= 6.0V 8 7 6 5 V_{GS}= 5.0V 4 3 2 V_{GS}= 4.5V 1 0 10 20 0 30 50 Drain - Source Voltage: V_{DS}[V]

Fig.8 Typical Output Characteristics(II)

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Fig.9 Typical Transfer Characteristics

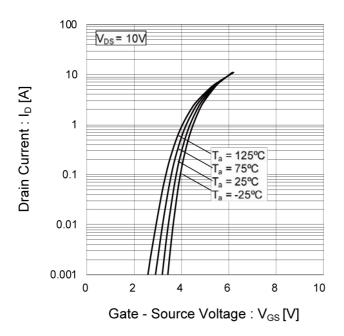


Fig.10 Gate Threshold Voltage vs.
Junction Temperature

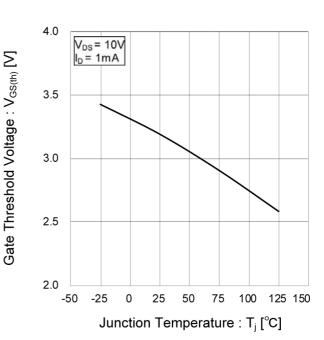


Fig.11 Forward Transfer Admittance vs.
Drain Current

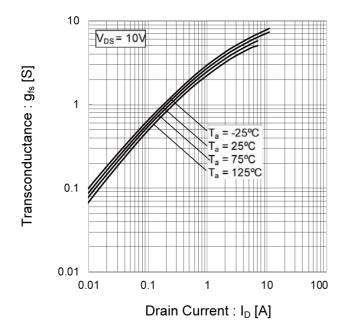


Fig.12 Static Drain - Source On - State Resistance vs. Drain Current

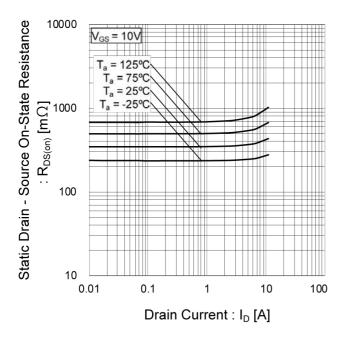


Fig.13 Static Drain - Source On - State Resistance vs. Gate Source Voltage

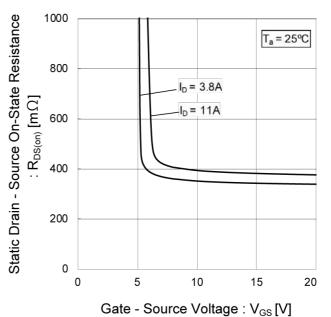


Fig.14 Static Drain - Source On - State Resistance vs. Junction Temperature

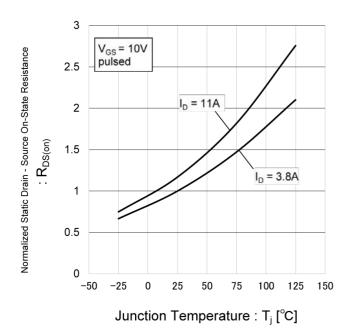


Fig.15 Typical Capacitance vs.

Drain - Source Voltage

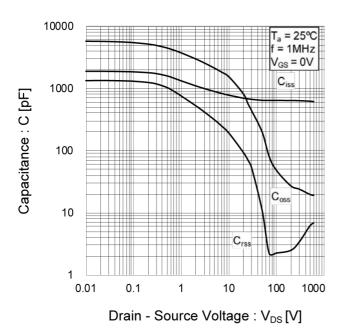


Fig.16 Switching Characteristics

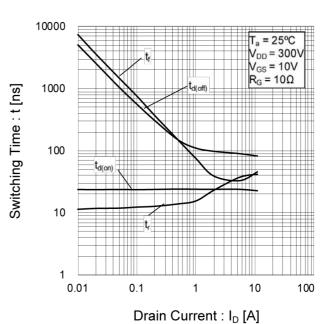
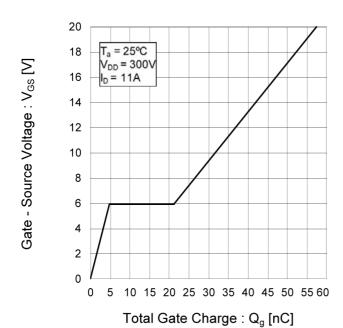


Fig.17 Typical Gate Charge



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Fig.18 Source Current vs. Source - Drain Voltage

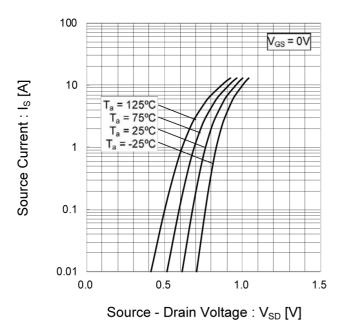
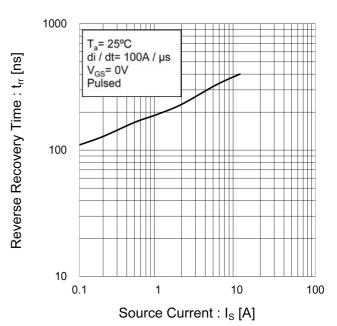


Fig.19 Reverse Recovery Time vs. Source Current



Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

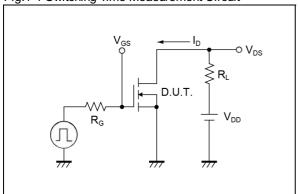


Fig.2-1 Gate Charge Measurement Circuit

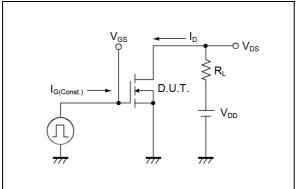


Fig.3-1 Avalanche Measurement Circuit

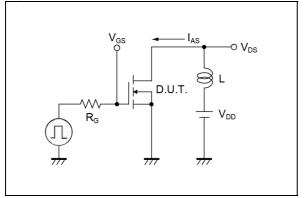


Fig.4-1 trr Measurement Circuit

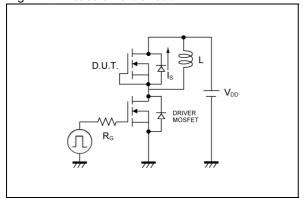


Fig.1-2 Switching Waveforms

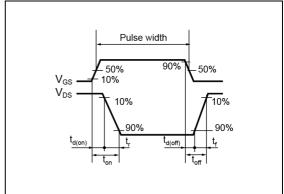


Fig.2-2 Gate Charge Waveform

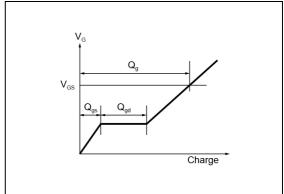


Fig.3-2 Avalanche Waveform

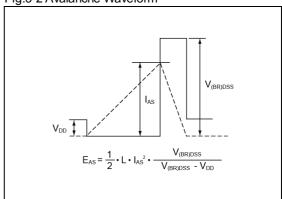
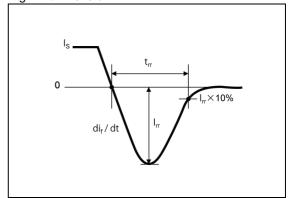
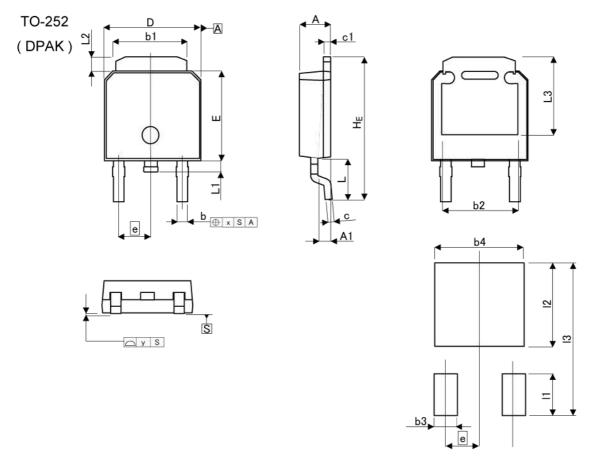


Fig.4-2 trr Waveform



Dimensions



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM -	MILIME	ETERS	INC	HES	
	MIN	MAX	MIN	MAX	
Α	2.20	2.40	0.087	0.094	
A1	0.70	1.10	0.028	0.043	
b	0.60	0.90	0.024	0.035	
b1	5.20	5.50	0.205	0.217	
b2	4.	80	0.1	89	
С	0.40	0.60	0.016	0.024	
c1	0.40	0.60	0.016	0.024	
D	6.40	6.80	0.252	0.268	
е	2.	30	0.0	91	
E	6.00	6.40	0.236	0.252	
HE	9.40	10.40	0.370	0.409	
L	2.	90	0.114		
L1	0.60	1.00	0.024	0.039	
L2	0.70	1.30	0.028	0.051	
L3	5.	30	0.209		
х	÷	0.25		0.010	
у	8	0.10	(5)	0.004	
DIA	MILIME	ETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
b3	¥	1.15	S#40	0.045	
b4	-	5.55	0.750	0.219	
11	-	2.77	S (#2)	0.109	
12	8	5.50	(8)	0.217	
13	#	10.40	7E0	0.409	

Dimension in mm/inches



Notice

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JAPAN	USA	EU	CHINA
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CLASSIV	CLASSIII	CLASSIII	CLASSIII

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 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
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- 8. Confirm that operation temperature is within the specified range described in the product specification.
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- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

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- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
 may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
 exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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Notice-PGA-E Rev.003

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